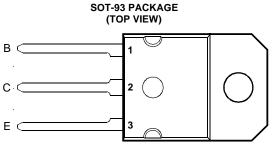
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- Designed for Complementary Use with the BD545 Series
- 85 W at 25°C Case Temperature
- 15 A Continuous Collector Current
- Customer-Specified Selections Available



Pin 2 is in electrical contact with the mounting base.

MDTRAA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT	
	BD546		-40	
Collector base veltare (I)	BD546A	V	-60	V
Collector-base voltage ($I_E = 0$)	BD546B	V _{сво}	-80	v
	BD546C		-100	
	BD546		-40	
Collector-emitter voltage $(I_B = 0)$ (see Note 1)	BD546A	N/	-60	V
	BD546B	V _{CEO}	-80	v
	BD546C		-100	
Emitter-base voltage	V _{EBO}	-5	V	
Continuous collector current			-15	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			85	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			3.5	W
Operating free air temperature range			-65 to +150	°C
Operating junction temperature range			-65 to +150	°C
Storage temperature range			-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds			260	°C

NOTES: 1. These values apply when the base-emitter diode is open circuited.

2. Derate linearly to 150°C case temperature at the rate of 0.68 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 28 mW/°C.

PRODUCT INFORMATION

Information is current as of publication date. Products conform to specifications in accordance with the terms of Power Innovations standard warranty. Production processing does not necessarily include testing of all parameters.



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electrical characteristics at 25°C case temperature

PARAMETER			TEST CONDITION	ONS	MIN	TYP	MAX	UNIT
				BD546	-40			
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = -30 mA (see Note 4)	I _B = 0	BD546A	-60			V
				BD546B	-80			·
				BD546C	-100			
	Collector-emitter cut-off current	V _{CE} = -40 V	$V_{BE} = 0$	BD546			-0.4	
		V _{CE} = -60 V	$V_{BE} = 0$	BD546A			-0.4	<u>س</u> ۸
ICES		V _{CE} = -80 V	$V_{BE} = 0$	BD546B			-0.4	mA
		V _{CE} = -100 V	$V_{BE} = 0$	BD546C			-0.4	
I _{CEO}	Collector cut-off	V _{CE} = -30 V	I _B = 0	BD546/546A			-0.7	
	current	V _{CE} = -60 V	I _B = 0	BD546B/546C			-0.7	mA
	Emitter cut-off	V _{EB} = -5 V	I _C = 0				-1	mA
I _{EBO}	current						-1	111A
	Forward current transfer ratio $V_{CE} = -4 V$ $V_{CE} = -4 V$ $V_{CE} = -4 V$	$V_{CE} = -4 V$	I _C = -1 A		60			
h _{FE}		$V_{CE} = -4 V$	I _C = -5 A	(see Notes 4 and 5)	25			
		$V_{CE} = -4 V$	I _C = -10 A		10			
M	Collector-emitter	I _B = -625 mA	I _C = -5 A	(see Notes 4 and 5)			-0.8	V
V _{CE(sat)}	saturation voltage	I _B = -2 A	I _C = -10 A				-1	v
V	Base-emitter	V _{CE} = -4 V	-4 V I _C = -10 A (s	(see Notes 4 and 5)			-1.8	V
V_{BE}	voltage			(See Notes 4 and 5)			-1.0	v
h	Small signal forward	V _{CE} = -10 V	$V_{CE} = -10 V$ $I_{C} = -0.5 A$	f = 1 kHz	20			
h _{fe}	current transfer ratio		iC = -0.3 A		20			
h _{fe}	Small signal forward	V _{CE} = -10 V	I _C = -0.5 A	f = 1 MHz	3			
i' 'fel	current transfer ratio	VCE10 V						

NOTES: 4. These parameters must be measured using pulse techniques, t_p = 300 $\mu s,$ duty cycle \leq 2%.

5. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

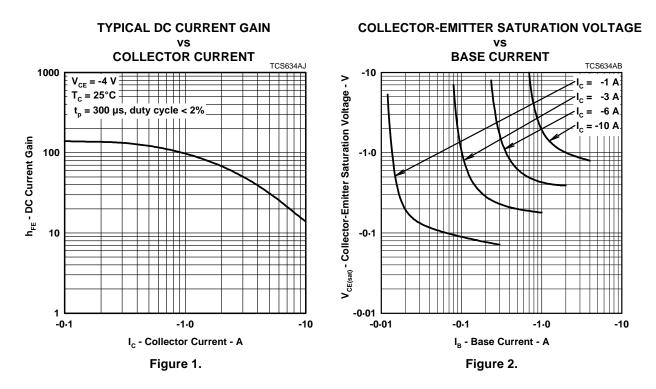
PARAMETER			ТҮР	MAX	UNIT
R _{θJC}	Junction to case thermal resistance			1.47	°C/W
R _{θJA}	Junction to free air thermal resistance			35.7	°C/W

resistive-load-switching characteristics at 25°C case temperature

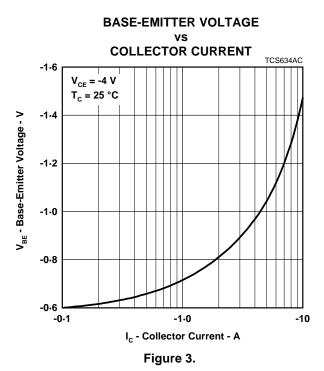
	PARAMETER	TEST CONDITIONS [†]			MIN	ТҮР	MAX	UNIT
t _{on}	Turn-on time	I _C = -6 A	I _{B(on)} = -0.6 A	$I_{B(off)} = 0.6 A$		0.4		μs
t _{off}	Turn-off time	$V_{BE(off)} = 4 V$	$R_L = 5 \Omega$	t_p = 20 µs, dc \leq 2%		0.7		μs

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

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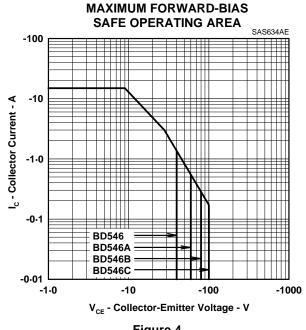


TYPICAL CHARACTERISTICS





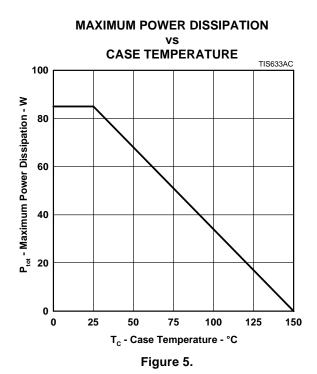
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MAXIMUM SAFE OPERATING REGIONS







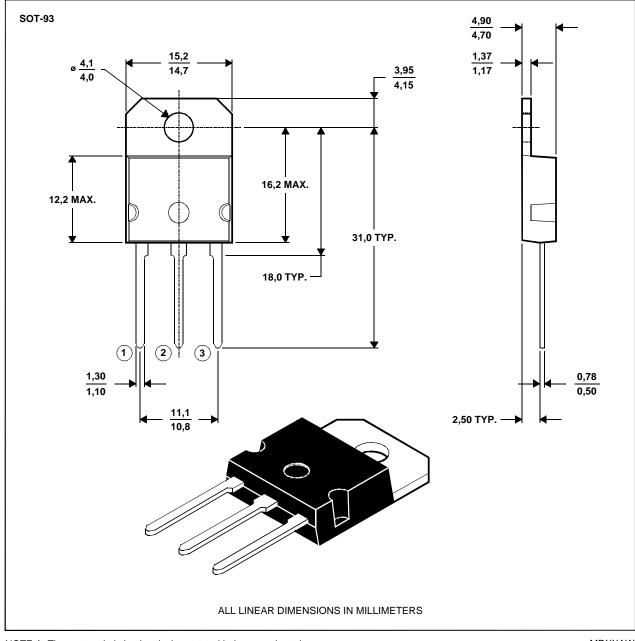
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MECHANICAL DATA

SOT-93

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTE A: The centre pin is in electrical contact with the mounting tab.

MDXXAW



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